NSN 5961-01-138-4665

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-138-4665 **Inclosure Material:** Metal **Overall Length:** 2.250 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.240 inches **Thread Size:** 0.375 inches and 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 240.0 reverse voltage, dc and 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 175.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0